

April 2009

MOCD213M Dual Channel Phototransistor Small Outline Surface Mount Optocouplers

Features

- U.L. recognized (File #E90700, Volume 2)
- VDE recognized (File #136616) (add option "V" for VDE approval, i.e, MOCD213VM)
- Dual channel coupler
- Convenient plastic SOIC-8 surface mountable package style
- Minimum current transfer ratio 100% with input current of 10mA
- Minimum BV_{CEO} of 70 Volts guaranteed
- Standard SOIC-8 footprint, with 0.050" lead spacing
- Compatible with dual wave, vapor phase and IR reflow soldering
- High input-output isolation of 2500 V_{AC(rms)} guaranteed

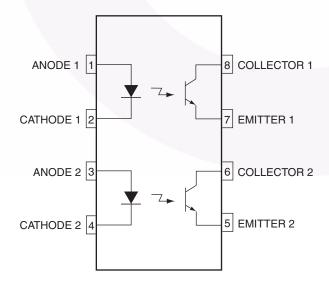
Applications

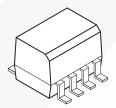
- Feedback control circuits
- Interfacing and coupling systems of different potentials and impedances
- General purpose switching circuits
- Monitor and detection circuits

Description

The MOCD213M device consists of two gallium arsenide infrared emitting diodes optically coupled to two monolithic silicon phototransistor detectors, in a surface mountable, small outline plastic package. It is ideally suited for high density applications and eliminates the need for through-the-board mounting.

Schematic





Absolute Maximum Ratings (T_A = 25°C Unless otherwise specified)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Rating	Value	Unit
EMITTER			
I _F	Forward Current – Continuous	60	mA
I _F (pk)	Forward Current – Peak (PW = 100µs, 120 pps)	1.0	Α
V _R	Reverse Voltage	6.0	V
P _D	LED Power Dissipation @ T _A = 25°C	90	mW
	Derate above 25°C	0.8	mW/°C
DETECTOR			
V _{CEO}	Collector-Emitter Voltage	70	V
V _{ECO}	Emitter-Base Voltage	7.0	V
I _C	Collector Current-Continuous	150	mA
P _D	Detector Power Dissipation @ T _A = 25°C	150	mW
	Derate above 25°C	1.76	mW/°C
TOTAL DEVICE			
V _{ISO}	Input-Output Isolation Voltage (f = 60Hz, t = 1 min.)	2500	Vac(rms)
P _D	Total Device Power Dissipation @ T _A = 25°C	250	mW
	Derate above 25°C	2.94	mW/°C
T _A	Ambient Operating Temperature Range	-40 to +100	°C
T _{stg}	Storage Temperature Range	-40 to +150	°C

Electrical Characteristics ($T_A = 25$ °C unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.*	Max.	Unit
EMITTER			1			
V _F	Input Forward Voltage	I _F = 30mA		1.25	1.55	V
I _R	Reverse Leakage Current	V _R = 6.0V		0.001	100	μΑ
С	Capacitance			18		pF
DETECTO	R		1			
I _{CEO1}	Collector-Emitter Dark Current	V _{CE} = 10 V, T _A = 25°C		1.0	50	nA
I _{CEO2}		V _{CE} = 10 V, T _A = 100°C		1.0		μΑ
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C = 100μA	70	120		V
BV _{ECO}	Emitter-Collector Breakdown Voltage	I _E = 100μA	7.0	7.8		V
C _{CE}	Collector-Emitter Capacitance	f = 1.0MHz, V _{CE} = 0V		7.0		pF
COUPLED			•			
CTR	Current Transfer Ratio ⁽⁴⁾	I _F = 10mA, V _{CE} = 10V	100			%
V _{CE (sat)}	Collector-Emitter Saturation Voltage	I _C = 2.0mA, I _F = 10mA		0.15	0.4	V
t _{on}	Turn-On Time	I_C = 2.0mA, V_{CC} = 10V, R_L = 100 Ω (Fig. 6)		3.0		μs
t _{off}	Turn-Off Time	I_C = 2.0mA, V_{CC} = 10V, R_L = 100 Ω (Fig. 6)		2.8		μs
t _r	Rise Time	I_C = 2.0mA, V_{CC} = 10V, R_L = 100 Ω (Fig. 6)		1.6		μs
t _f	Fall Time	I_C = 2.0mA, V_{CC} = 10V, R_L = 100 Ω (Fig. 6)		2.2		μs
V _{ISO}	Isolation Surge Voltage ⁽¹⁾⁽²⁾⁽³⁾	f = 60Hz, t = 1 min.	2500			Vac(rms)
R _{ISO}	Isolation Resistance ⁽²⁾	V _{I-O} = 500V	10 ¹¹			Ω
C _{ISO}	Isolation Capacitance ⁽²⁾	V _{I-O} = 0V, f = 1MHz		0.2		pF

^{*}Typical values at T_A = 25°C

Notes:

- 1. Input-Output Isolation Voltage, V_{ISO} , is an internal device dielectric breakdown rating.
- 2. For this test, Pins 1, 2, 3 and 4 are common and Pins 5, 6, 7 and 8 are common.
- 3. V_{ISO} rating of 2500 $V_{AC(rms)}$ for t = 1 min. is equivalent to a rating of 3,000 $V_{AC(rms)}$ for t = 1 sec.
- 4. Current Transfer Ratio (CTR) = $I_C/I_F \times 100\%$.

Typical Performance Curves

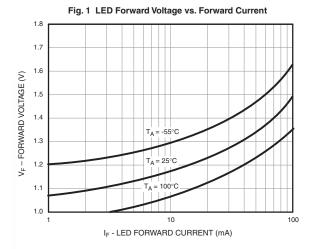


Fig. 2 Output Curent vs. Input Current

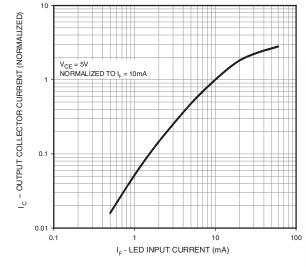


Fig. 3 Output Current vs. Ambient Temperature

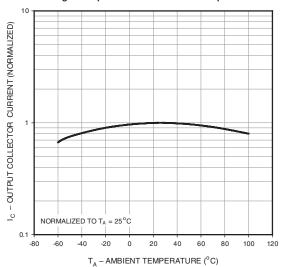


Fig. 4 Output Current vs. Collector - Emitter Voltage

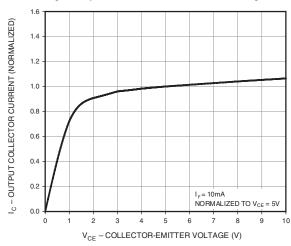
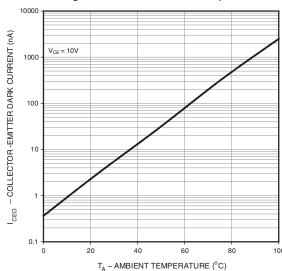


Fig. 5 Dark Current vs. Ambient Temperature

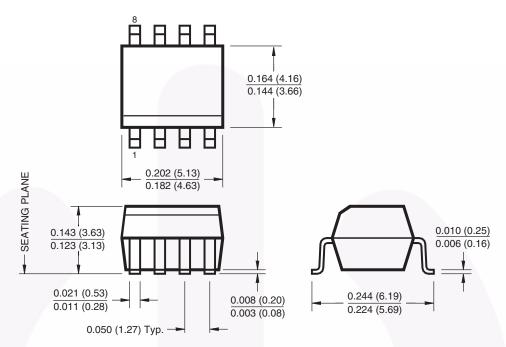


TEST CIRCUIT $V_{CC} = 10V$ INPUT PULSE OUTPUT OUTPUT PULSE $Adjust \ I_F \ to \ produce \ I_C = 2mA$ OUTPUT PULSE

Figure 6. Switching Time Test Circuit and Waveform

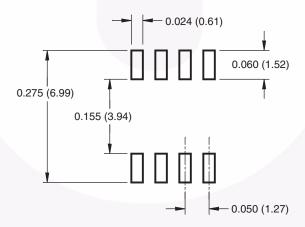
Package Dimensions

8-pin SOIC Surface Mount



Lead Coplanarity: 0.004 (0.10) MAX

Recommended Pad Layout



Dimensions in inches (mm).

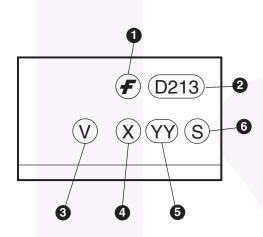
Package drawings are provided as a service to customers considering Fairchild components. Drawings may change in any manner without notice. Please note the revision and/or date on the drawing and contact a Fairchild Semiconductor representative to verify or obtain the most recent revision. Package specifications do not expand the terms of Fairchild's worldwide terms and conditions, specifically the warranty therein, which covers Fairchild products.

Always visit Fairchild Semiconductor's online packaging area for the most recent package drawings: http://www.fairchildsemi.com/packaging/

Ordering Information

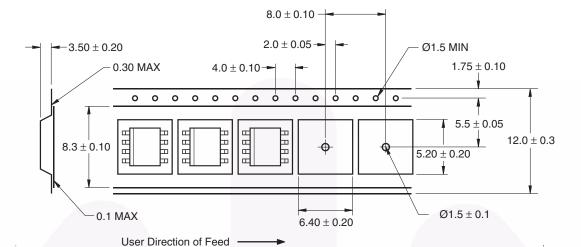
Option	Order Entry Identifier	Description	
V	V	VDE 0884	
R2	R2	Tape and reel (2500 units per reel)	
R2V	R2V	VDE 0884, Tape and reel (2500 units per reel)	

Marking Information



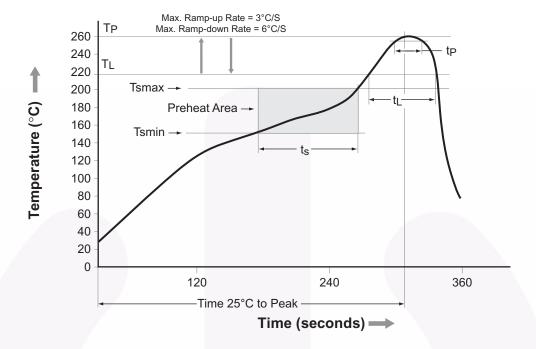
Defini	tions		
1	Fairchild logo		
2	Device number		
3	VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table)		
4	One digit year code, e.g., '8'		
5	Two digit work week ranging from '01' to '53'		
6	Assembly package code		

Carrier Tape Specifications



Dimensions in mm

Reflow Profile



Profile Freature	Pb-Free Assembly Profile	
Temperature Min. (Tsmin)	150°C	
Temperature Max. (Tsmax)	200°C	
Time (t _S) from (Tsmin to Tsmax)	60-120 seconds	
Ramp-up Rate (t _L to t _P)	3°C/second max.	
Liquidous Temperature (T _L)	217°C	
Time (t _L) Maintained Above (T _L)	60-150 seconds	
Peak Body Package Temperature	260°C +0°C / -5°C	
Time (t _P) within 5°C of 260°C	30 seconds	
Ramp-down Rate (T _P to T _L)	6°C/second max.	
Time 25°C to Peak Temperature	8 minutes max.	





TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

Auto-SPM™ Build it Now™ CorePLUS™

Global Power Resource SM CorePOWER™ Green FPS™ CROSSVOLT™

CTL™ Current Transfer Logic™ EcoSPARK[®] EfficentMax™

EZSWITCH™*

Fairchild® Fairchild Semiconductor® FACT Quiet Series™ FACT®

FAST® FastvCore™ FETBench™

FlashWriter® FPS™

F-PESTM FRFET®

Green FPS™ e-Series™

Gmax™ GTO™ IntelliMAX™ ISOPLANAR™ MegaBuck™ MICROCOUPLER™

MicroFET™ MicroPak™ MillerDrive™ MotionMax™ Motion-SPM™ OPTOLOGIC® OPTOPLANAR®

PDP SPM™ Power-SPM™ PowerTrench® PowerXS™

Programmable Active Droop™

QFET QS™ Quiet Series™ RapidConfigure™

Saving our world, 1mW/W/kW at a time™

SmartMax™ SMART START™ SPM[®] STEALTH™

SuperFET™ SuperSOT™-3 SuperSOT™-6 SuperSOT™-8 SupreMOS™ SyncFET™ Sync-Lock™ SYSTEM

The Power Franchise®

bwer franchise TinyBoost™ TinyBuck™ TinyLogic[®] TINYOPTO™ TinyPower™ TinyPWM™ TinyWire™ TriFault Detect™ TRUECURRENT™* սSerDes™

UHC Ultra FRFET™ UniFET™ VCX™ VisualMax™ XSTM

* Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- 2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com,

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS

Definition of Torme

Definition of Terms				
Datasheet Identification	Product Status	uct Status Definition		
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.		
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.		
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.		
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.		

Rev. 140